WHAT IS CLAIMED IS:

A photovoltaic device for conversion of an incident wavelength of
electromagnetic radiation to electricity, the photovoltaic device comprising:

 an absorber of the incident wavelength of electromagnetic radiation;
 a trimetasphere, the trimetasphere in electron transferring contact with

an anode in electrical contact with the trimetasphere; and a cathode in electrical contact with the absorber.

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- 2. The photovoltaic device of claim 1, wherein the absorber and trimetasphere are a heterojunction.
- 3. The photovoltaic device of claim 1, wherein the absorber and trimetasphere are a blended junction
 - 4. The photovoltaic device of claim 1, wherein the trimetasphere includes a carbon-cage structure with an interior volume, wherein the carbon-cage structure encapsulates one or more metal atoms or ions complexed with a non-carbon heteroatom or ion.
 - 5. The photovoltaic device of claim 4, wherein the trimetasphere has a general formula $A_{3-n}X_nN@C_m$, wherein n ranges from 0 to 3, A and X are a trivalent metal, m is between about 60 and about 200, and N is the non-carbon heteroatom or ion.

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- 6. The photovoltaic device of claim 5, wherein N is nitrogen.
- 7. The photovoltaic device of claim 5, wherein the trivalent metal is a rare earth metal or a group IIIB metal.

- 8. The photovoltaic device of claim 7, wherein A is selected from the group consisting of Scandium, Yttrium, Lanthanum, Cerium, Praseodymium, Neodymium, Gadolinium, Dysprosium, Holmium, Erbium, Thulium, and Ytterbium.
- 5 9. The photovoltaic device of claim 8, wherein A is selected from the group consisting of Erbium, Holmium, Scandium and Yttrium.
 - 10. The photovoltaic device of claim 7, wherein X is selected from the group consisting of Scandium, Yttrium, Lanthanum, Cerium, Praseodymium, Neodymium, Gadolinium, Dysprosium, Holmium, Erbium, Thulium, and Ytterbium.
 - 11. The photovoltaic device of claim 1, wherein the trimetasphere has a A^1 , A^2 , A^3 complexed structure where A^1 , A^2 , and A^3 are the same atoms or ions.
- 15 12. The photovoltaic device of claim 11, wherein the trimetasphere has a A¹, A², A³ complexed structure including a heteroatom or ion.
 - 13. An electrical circuit comprising:

an absorber of incident electromagnetic radiation;

a trimetasphere-containing material in electron transferring contact with the absorber;

an anode;

a cathode; and

a current path from the anode to the cathode.

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- 14. The electrical circuit of claim 13, wherein the absorber and trimetasphere-containing material are a heterojunction.
- 15. The electrical circuit of claim 13, wherein the absorber and trimetasphere-containing material are a blended junction.

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- 16. The electrical circuit of claim 13, wherein the anode is in electrical contact with the trimetasphere-containing material.
- 17. The electrical circuit of claim 13, wherein the cathode is in electrical contact with the absorber.
 - 18. The electrical circuit of claim 13, wherein a trimetasphere in the trimetasphere-containing material includes a carbon-cage structure with an interior volume, wherein the carbon-cage structure encapsulates one or more metal atoms or ions complexed with a non-carbon hetero atom or ion.
 - 19. The electrical circuit of claim 18, wherein the trimetasphere has a general formula A_{3-n}X_nN@C_m, wherein n ranges from 0 to 3, A and X are a trivalent metal, m is between about 60 and about 200, and N is the non-carbon heteroatom or ion.

20. The electrical circuit of claim 19, wherein N is nitrogen.

- 21. The electrical circuit of claim 19, wherein the trivalent metal is a rare earth metal or a group IIIB metal.
- 22. The electrical circuit of claim 21, wherein A is selected from the group consisting of Scandium, Yttrium, Lantharium, Cerium, Praseodymium, Neodymium, Gadolinium, Dysprosium, Holmium, Erbium, Thulium, and Ytterbium.
- 25 23. The electrical circuit of claim 22, wherein A is selected from the group consisting of Erbium, Holmium, Scandium and Yttrium.
 - 24. The electrical circuit of claim 21, wherein X is selected from the group consisting of Scandium, Yttrium, Lantharnum, Cerium, Praseodymium, Neodymium, Gadolinium, Dysprosium, Holmium, Erbirum, Thulium, and Ytterbirum.

- 25. The electrical circuit of claim 13, wherein a trimetasphere of the trimetasphere-containing material has a A^1 , A^2 , A^3 complexed structure where A^1 , A^2 , and A^3 are the same atoms or ions.
- 5 26. The electrical circuit of claim 25, wherein the trimetasphere has a A¹, A², A³ complexed structure including a heteroatom or ion.
 - 27. A method of converting incident electromagnetic radiation to an electrical signal, the method comprising:
- absorbing the incident electromagnetic radiation by an absorber or a photoactive material to produce an electron-hole pair;

transferring an electron in a Lowest Unoccupied Molecular Orbital (LUMO) of the absorber or the photoactive material across a band gap to a trimetasphere-containing material;

injecting an electron from the trimetasphere-containing material into an anode

transferring a hole in a Highest Occupied Molecular Orbital (HOMO) of the absorber or the photoactive material to a cathode; and completing a circuit between the anode and the cathode.

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- 28. The method of claim 27, wherein the absorber and the trimetasphere-containing material are a heterojunction.
- 29. The method of claim 27, wherein the absorber and thetrimetasphere-containing material are a blended junction.
 - 30. The method of claim 27, wherein a trimetasphere in the trimetasphere-containing material includes a carbon-cage structure with an interior volume, wherein the carbon-cage structure encapsulates one or more metal atoms or ions complexed with a non-carbon heteroatom or ion.

- 31. The method of claim 30, wherein the trimetasphere has a general formula A_{3-n}X_nN@C_m, wherein n ranges from 0 to 3, A and X are a trivalent metal, m is between about 60 and about 200, and N is the non-carbon heteroatom or ion.
- 5 32. The method of claim 31, wherein N is nitrogen.
 - 33. The method of claim 31, wherein the trivalent metal is a rare earth metal or a group IIIB metal.
- 10 34. The method of claim 33, wherein A is selected from the group consisting of Scandium, Yttrium, Lanthanum, Cerium, Praseodymium, Neodymium, Gadolinium, Dysprosium, Holmium, Erbium, Thulium, and Ytterbium.
- 35. The method of claim 34, wherein A is selected from the group consisting of Erbium, Holmium, Scandium and Yttrium.
 - 36. The method of claim 33, wherein X is selected from the group consisting of Scandium, Yttrium, Lanthanum, Cerium, Praseodymium, Neodymium, Gadolinium, Dysprosium, Holmium, Erbium, Thulium, and Ytterbium.
 - 37. The method of claim 27, wherein the incident electromagnetic radiation is a wavelength in a visible spectrum or an ultraviolet spectrum.
- 38. The method of claim 27, wherein a trimetasphere of the
 trimetasphere-containing material has a A¹, A², A³ complexed structure where A¹, A², and A³ are the same atoms or ions.
 - 39. The method of claim 38, wherein the trimetasphere has a A¹, A², A³ complexed structure including a heteroatom or ion.